

# **IXTA3N110**

## **IXTA3N110 Information**





Request a Quote

# **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



# **IXTA3N110** Specifications

Manufacturer Part Number	IXTA3N110
Manufacturer	IXYS
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-263-3, D2Pak (2 Leads + Tab), TO-263AB
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	1100V
Current - Continuous Drain (Id) @ 25°C	3A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	42nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1350pF @ 25V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	150W (Tc)
Rds On (Max) @ Id, Vgs	4 Ohm @ 1.5A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	TO-263 (IXTA)
Package / Case	TO-263-3, D2Pak (2 Leads + Tab), TO-263AB
	Report errors?

#### **IXTA3N110** Guarantees



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

# SERVICE EVARANTEE

#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

## IXTA3N110 Payment Methods



# **IXTA3N110 Shipping Methods**



If you have any question about IXTA3N110, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com